

TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington)

2SD2131

High-Power Switching Applications

Hammer Drive, Pulse Motor Drive Applications

- High DC current gain: $hFE = 2000$ (min) ($V_{CE} = 3$ V, $I_C = 3$ A)
- Low saturation voltage: $V_{CE(\text{sat})} = 1.5$ V (max) ($I_C = 3$ A)
- Zener diode included between collector and base.
- Unclamped inductive load energy: $E = 150$ mJ (min)

Absolute Maximum Ratings (T_c = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	60 ± 10	V
Collector-emitter voltage		V_{CEO}	60 ± 10	V
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC	I_C	5	A
	Pulse	I_{CP}	8	
Base current		I_B	0.5	A
Collector power dissipation	$T_A = 25^\circ C$	P_C	2.0	W
	$T_C = 25^\circ C$		30	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55 to 150	°C

Technical drawing of a transistor component showing dimensions and lead labels. The drawing includes:

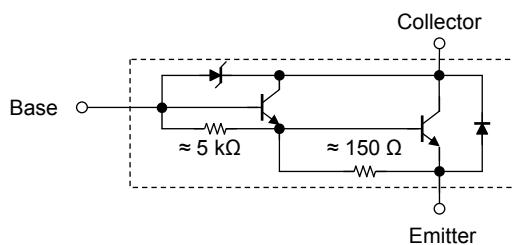
- Top view dimensions: 10 ± 0.3 mm width, 3.2 ± 0.2 mm height, 3.9 ± 0.3 mm thickness, and 15 ± 0.3 mm total height.
- Bottom view dimensions: 5.6 MAX. width, 1.1 lead spacing, 0.75 ± 0.15 mm thickness, 2.54 ± 0.25 mm lead spacing, and 13.0 MIN. total height.
- Lead dimensions: 0.75 ± 0.15 mm thickness, 2.6 mm lead length, and 4.5 ± 0.2 mm total lead length.
- Lead labels: 1. BASE, 2. COLLECTOR, 3. Emitter.

Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

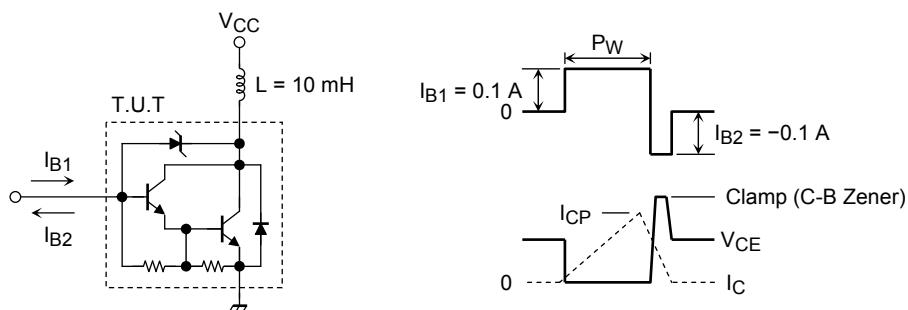
Equivalent Circuit



Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 45\text{ V}$, $I_E = 0$	—	—	10	μA
Collector cut-off current	I_{CEO}	$V_{CE} = 45\text{ V}$, $I_B = 0$	—	—	10	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 6\text{ V}$, $I_C = 0$	—	—	2.5	mA
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	$I_C = 1\text{ mA}$, $I_E = 0$	50	60	70	V
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	$I_C = 10\text{ mA}$, $I_B = 0$	50	60	70	V
DC current gain	h_{FE} (1)	$V_{CE} = 3\text{ V}$, $I_C = 3\text{ A}$	2000	—	15000	
	h_{FE} (2)	$V_{CE} = 3\text{ V}$, $I_C = 5\text{ A}$	1000	—	—	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$ (1)	$I_C = 3\text{ A}$, $I_B = 6\text{ mA}$	—	1.1	1.5	V
	$V_{CE(\text{sat})}$ (2)	$I_C = 5\text{ A}$, $I_B = 20\text{ mA}$	—	1.3	2.5	
Base-emitter saturation voltage	$V_{BE(\text{sat})}$	$I_C = 3\text{ A}$, $I_B = 6\text{ mA}$	—	1.7	2.5	V
Unclamped inductive load energy	$E_{\text{S/B}}$	(Note 1)		150	—	—
Switching time	Turn-on time	t_{on}				μs
	Storage time	t_{stg}				
	Fall time	t_f				

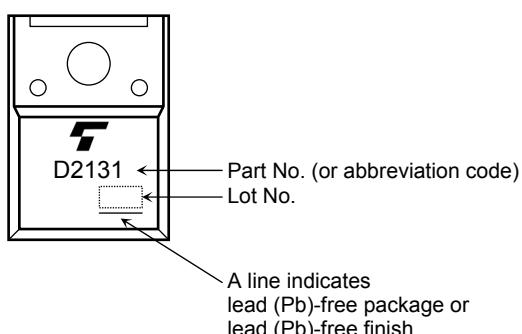
Note 1: Measurement circuit for unclamped inductive load energy

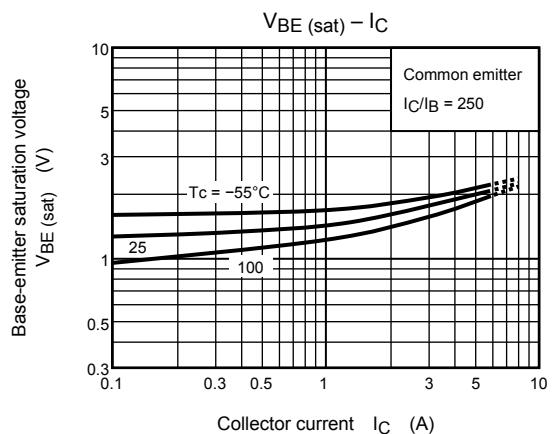
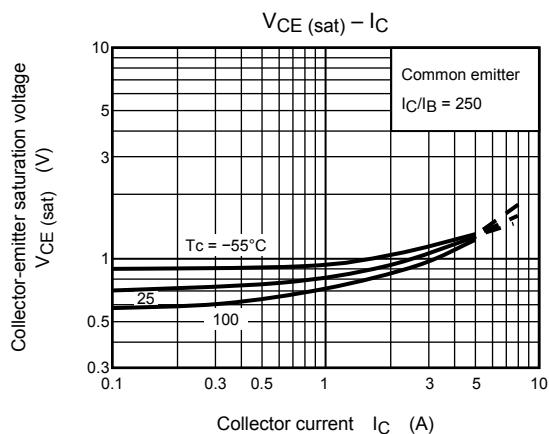
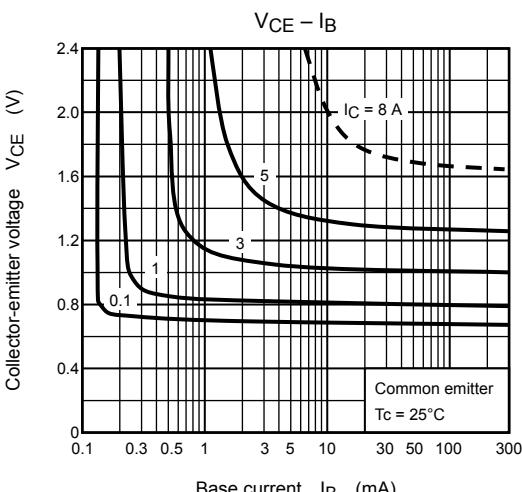
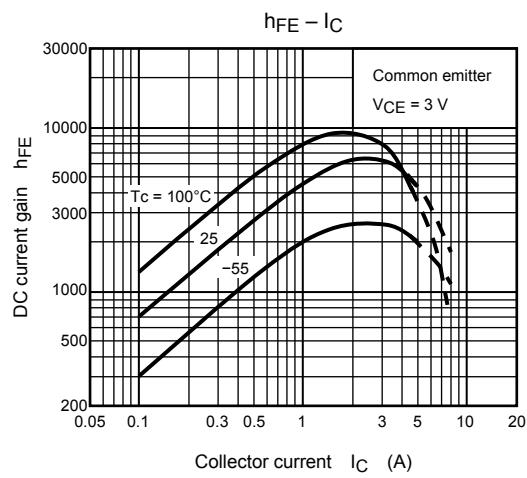
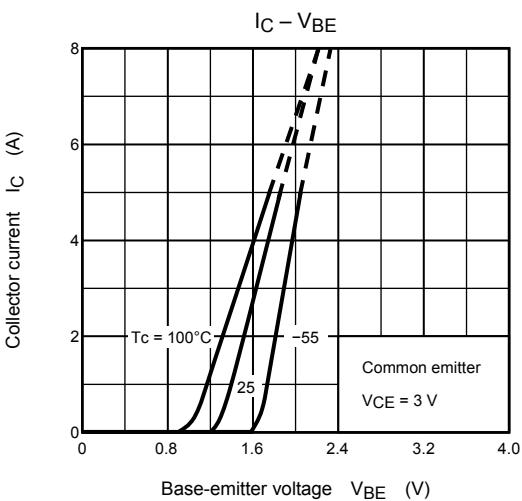
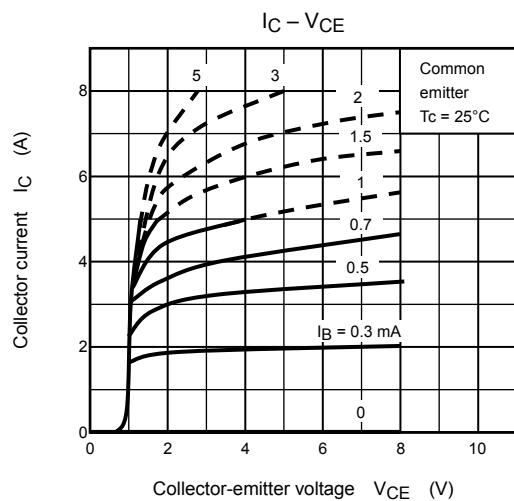


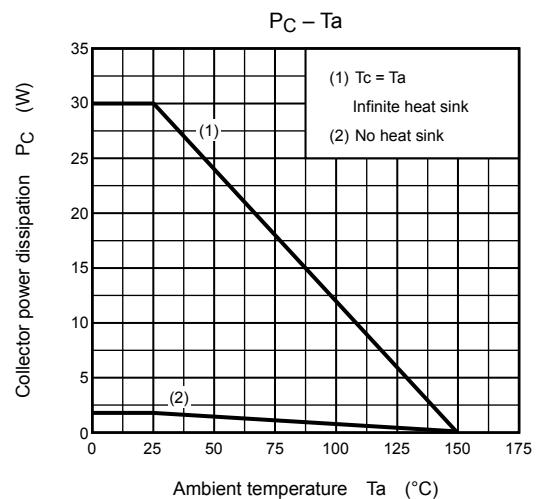
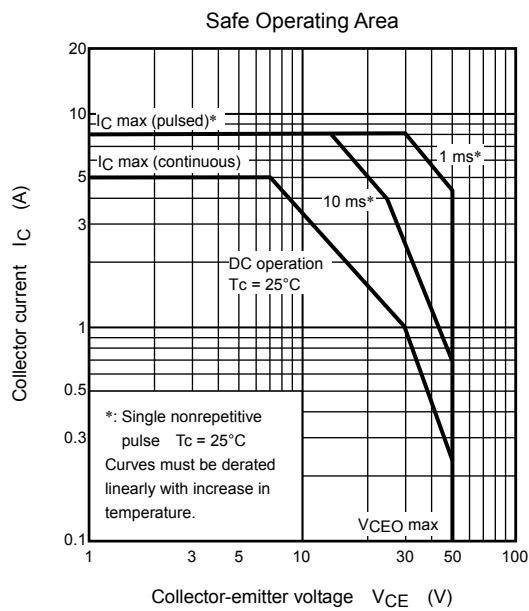
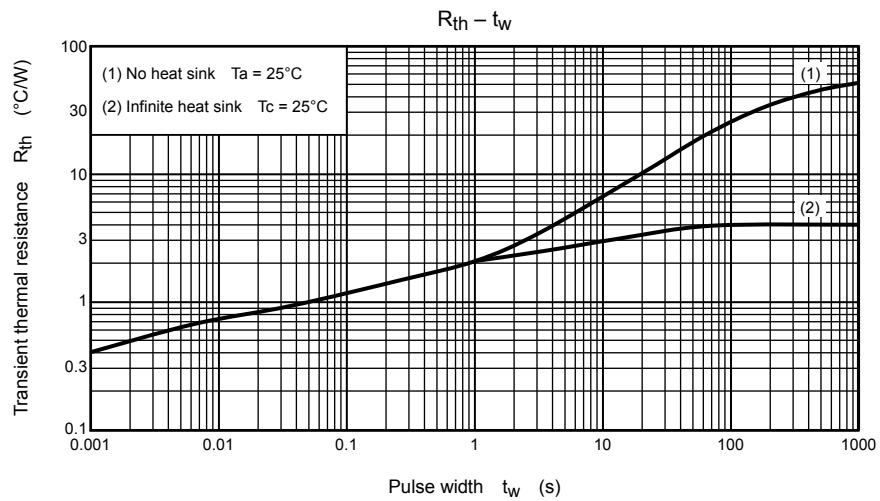
Note 2: (1) Pulse width adjusted for desired I_{CP} ($I_{CP} = 5.47\text{ A min}$)

$$(2) E = 1/2 L I_{CP}^2$$

Marking







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